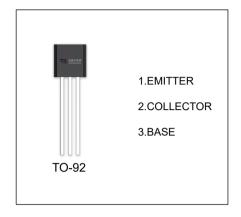


# BC636 / BC638 / BC640 TRANSISTOR (PNP)

#### **FEATURES**

High current transistors



#### **ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
BC636	TO-92	Bulk	1000pcs/Bag
BC636-TA	TO-92	Tape	2000pcs/Box
BC638	TO-92	Bulk	1000pcs/Bag
BC638-TA	TO-92	Tape	2000pcs/Box
BC640	TO-92	Bulk	1000pcs/Bag
BC640-TA	TO-92	Tape	2000pcs/Box

### MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter		Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	BC636	-45	
		BC638	-60	V
		BC640	-100	
V <sub>CEO</sub>	Collector-Emitter Voltage	BC636	-45	
		BC638	-60	V
		BC640	-80	
V <sub>EBO</sub>	Emitter-Base Voltage		-5	V
Ic	Collector Current -Continuous		-1	А
Pc	Collector Power Dissipation		0.83	W
R <sub>0 JA</sub>	Thermal Resista nce, junction to Amb	ient	150	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range		-55~+150	℃



## $T_a$ =25 $^{\circ}$ C unless otherwise specified

Parameter	Symbol	Test conditions	Mi	п Тур	Max	Unit
Collector-base breakdown voltage		I <sub>C</sub> =-100μA,I <sub>E</sub> =0 BC6	36 -4	5		
	V <sub>(BR)CBO</sub>	BC6	38 -6	o		V
		BC6	40 -10	0		
		$I_C = -1 \text{mA}, I_B = 0$ BC6	36 -4	5		
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	BC6	38 -6	0		V
		BC6	40 -8	0		
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-100μA,I <sub>C</sub> =0	-5	;		V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-30V,I <sub>E</sub> =0			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}$ = -5 $V$ , $I_{C}$ =0			- 0.1	μA
	h <sub>FE(1)</sub>	$V_{CE}$ = -2V, $I_{C}$ =- 5mA	40	)		
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> = -2V,I <sub>C</sub> =- 150mA		3	250	
	h <sub>FE(3)</sub>	V <sub>CE</sub> = -2V,I <sub>C</sub> =- 500mA	2	5		
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =- 500mA,I <sub>B</sub> = -50mA			-0.5	V
Base-emitter voltage	$V_{BE}$	$V_{CE} = -2V, I_{C} = -500 \text{mA}$			- 1	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -5V,I <sub>C</sub> =- 50mA,f=100MHz		0		MHz

### CLASSIFICATION OF hFE(2)

Rank	BC636-10	BC636-16, BC638-16, BC640-16
Range	63-160	100-250